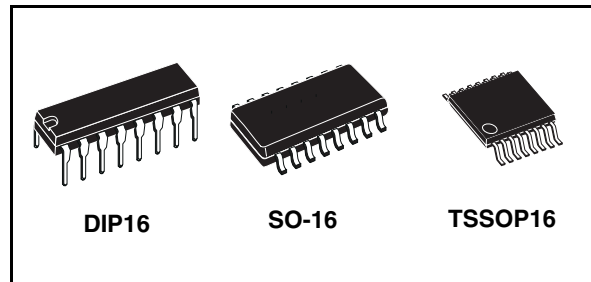


8-bit PISO shift register

Features

- High speed:
 - $t_{PD} = 15 \text{ ns}$ (typ.) at $V_{CC} = 6 \text{ V}$
- Low power dissipation:
 - $I_{CC} = 4 \mu\text{A}$ (Max.) at $T_A = 25 \text{ }^\circ\text{C}$
- High noise immunity:
 - $V_{NIH} = V_{NIL} = 28 \% V_{CC}$ (Min.)
- Symmetrical output impedance:
 - $|I_{OH}| = I_{OL} = 4 \text{ mA}$ (Min)
- Balanced propagation delays:
 - $t_{PLH} \cong t_{PHL}$
- Wide operating voltage range:
 - V_{CC} (Opr) = 2 V to 6 V
- Pin and function compatible with 74 SERIES 165



Description

The M74HC165 is an high speed CMOS 8 BIT PISO SHIFT REGISTER fabricated with silicon gate C²MOS technology.

This device contains eight clocked master slave RS flip-flops connected as a shift register, with auxiliary gating to provide over-riding asynchronous parallel entry. Parallel data enters when the shift/load input is low.

The parallel data can change while shift/load is low, provided that the recommended set-up and hold times are observed. For clocked operation, shift/load must be high. The two clock input perform identically; one can be used as a clock inhibit by applying a high signal; to permit this operation clocking is accomplished through a 2 input nor gate.

To avoid double clocking, however, the inhibit signal should only go high while the clock is high. Otherwise the rising inhibit signal will cause the same response as rising clock edge.

All inputs are equipped with protection circuits against static discharge and transient excess voltage.

Order codes

Part number	Package	Packaging
M74HC165B1R	DIP16	Tube
M74HC165M1R	SO-16	Tube
M74HC165RM13TR	SO-16	Tape and reel
M74HC165TTR	TSSOP16	Tape and reel

Contents

- 1 Logic symbols and I/O equivalent circuit 3**
- 2 Pin settings 4**
 - 2.1 Pin connection 4
 - 2.2 Pin description 4
- 3 Logic states 5**
 - 3.1 Truth table 5
 - 3.2 Logic diagram 5
 - 3.3 Timing chart 6
- 4 Maximum rating 7**
 - 4.1 Recommended operating conditions 7
- 5 Electrical characteristics 8**
- 6 Test circuit 10**
- 7 Waveforms 11**
- 8 Package mechanical data 13**
- 9 Revision history 17**

1 Logic symbols and I/O equivalent circuit

Figure 1. IEC logic symbols

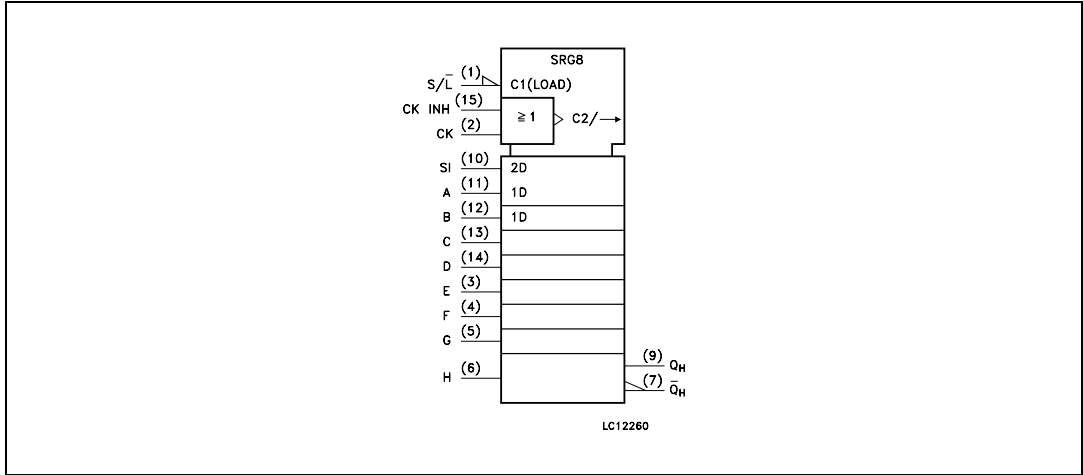
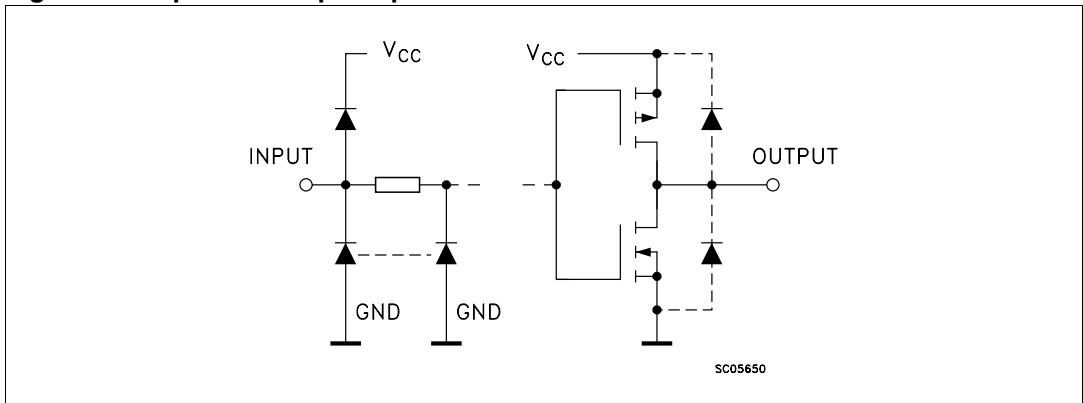


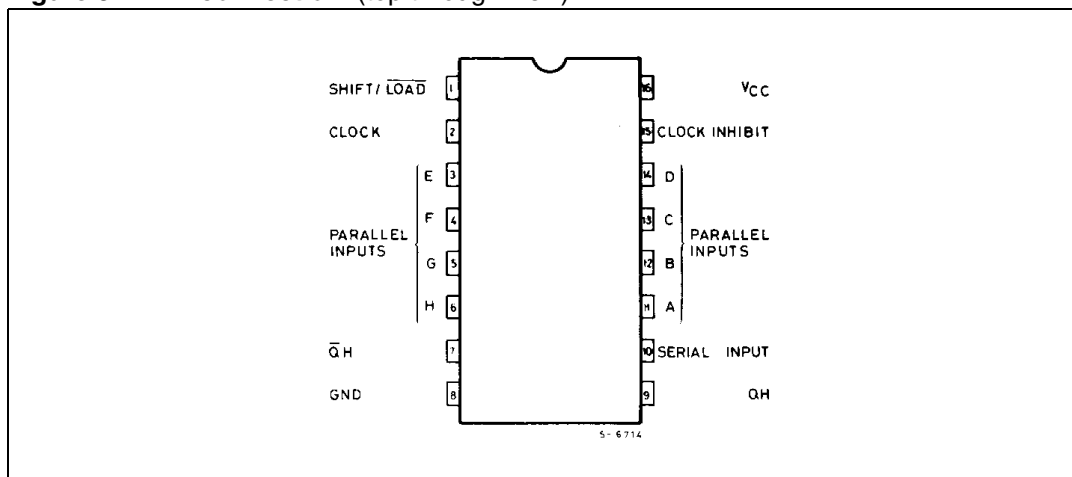
Figure 2. Input and output equivalent circuit



2 Pin settings

2.1 Pin connection

Figure 3. Pin connection (top through view)



2.2 Pin description

Table 1. Pin description

Pin N°	Symbol	Name and function
1	SHIFT/LOAD	Data Inputs
2	CLOCK	Clock Input (LOW to HIGH, Edge Triggered)
7	\overline{QH}	Complementary output
9	QH	Serial output
10	SI	Serial input
11, 12, 13, 14, 3, 4, 5, 6	A to H	Parallel Data Inputs
15	CLOCK INH	Clock Inhibit
8	GND	Ground (0V)
16	Vcc	Positive Supply Voltage

3 Logic states

3.1 Truth table

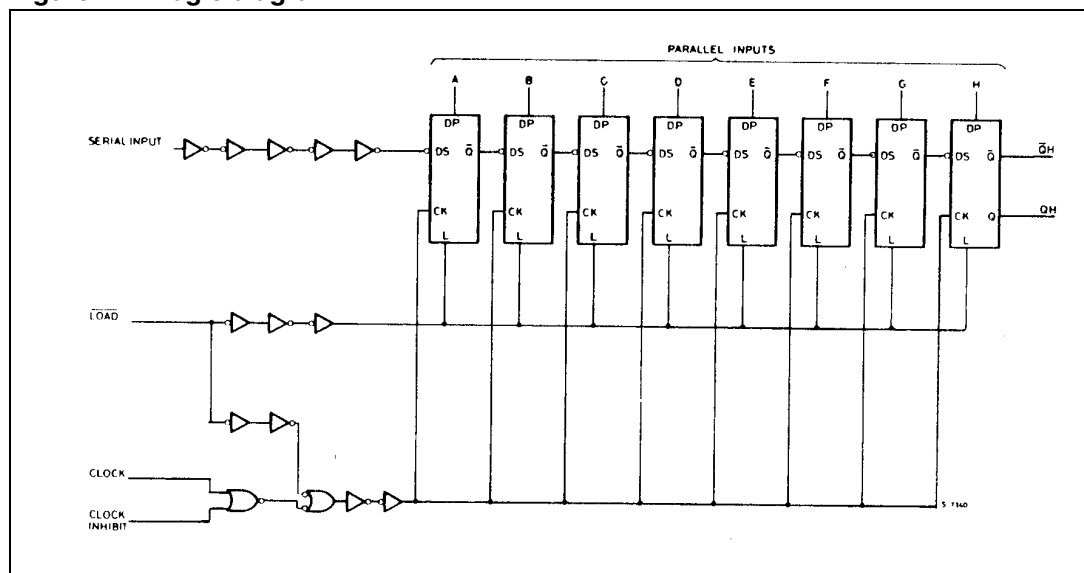
Table 2. Truth table

Inputs					Internal outputs		Outputs
Shift /Load	Clock INH	Clock	SI	A.....H	QA	QB	QH
L	X	X	X	a.....h	a	b	h
H	L		H	X	H	QAn	QGn
H	L		L	X	L	QAn	QGn
H		L	H	X	H	QAn	QGn
H		L	L	X	L	QAn	QGn
H	X	H	X	X	No change		
H	H	X	X	X	No change		

Note: a.....h : The level of steady input voltage at inputs a through respectively QAn - QGn : The level of QA - QG, respectively, before the most-recent transition of the clock

3.2 Logic diagram

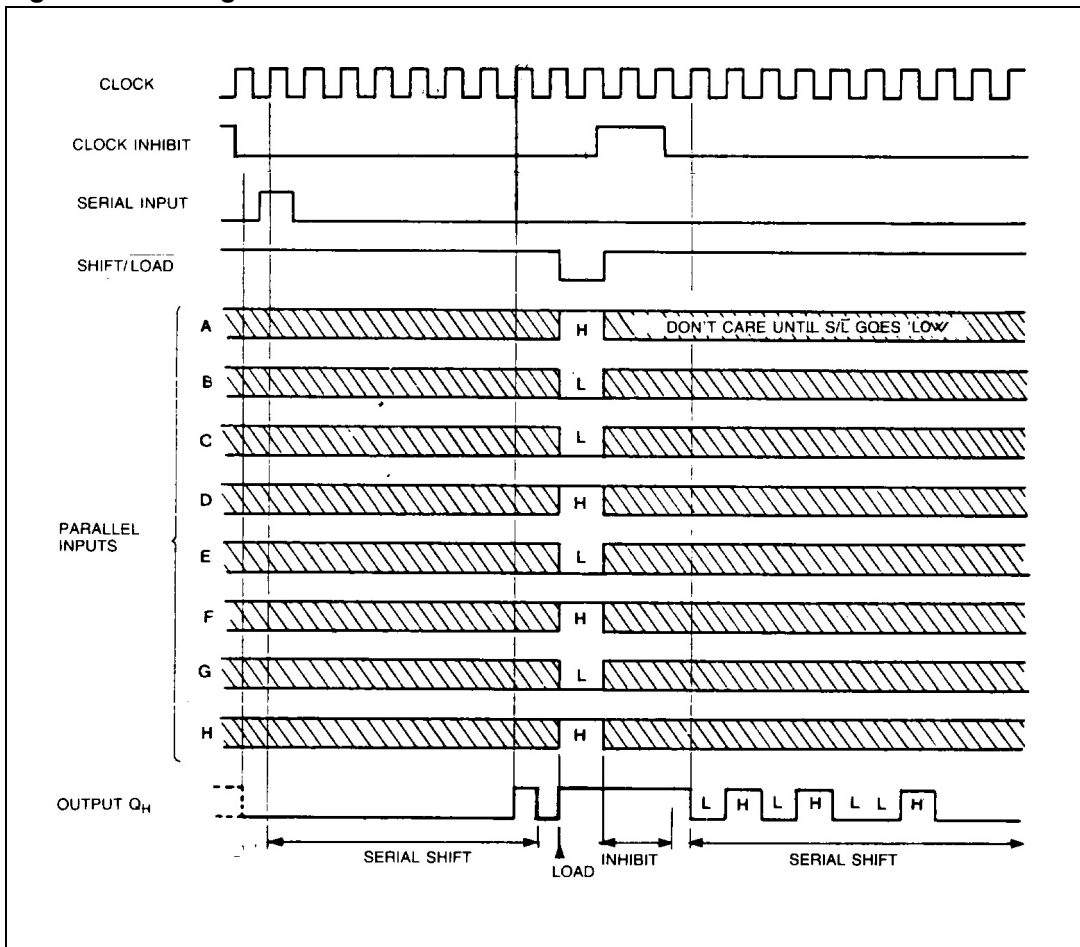
Figure 4. Logic diagram



Note: This logic diagram has not to be used to estimate propagation delays

3.3 Timing chart

Figure 5. Timing chart



4 Maximum rating

Stressing the device above the rating listed in the “absolute maximum ratings” table may cause permanent damage to the device. these are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. exposure to absolute maximum rating conditions for extended periods may affect device reliability. refer also to the STMicroelectronics sure program and other relevant quality documents.

Table 3. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage	-0.5 to +7	V
V_I	DC input voltage	-0.5 to $V_{CC} + 0.5$	V
V_O	DC output voltage	-0.5 to $V_{CC} + 0.5$	V
I_{IK}	DC input diode current	± 20	mA
I_{OK}	DC output diode current	± 20	mA
I_O	DC output current	± 25	mA
I_{CC} or I_{GND}	DC V_{CC} or ground current	± 50	mA
P_D	Power dissipation	500 ⁽¹⁾	mW
T_{stg}	Storage temperature	-65 to +150	°C
T_L	Lead temperature (10 sec)	300	°C

1. (*) 500mW at 65 °C; derate to 300mW by 10mW/°C from 65°C to 85°C

4.1 Recommended operating conditions

Table 4. Recommended operating conditions

Symbols	Parameter	Value	Unit	
V_{CC}	Supply voltage	2 to 6	V	
V_I	Input voltage	0 to V_{CC}	V	
V_O	Output voltage	0 to V_{CC}	V	
T_{op}	Operating temperature	-55 to 125	°C	
t_r, t_f	Input rise and fall time	$V_{CC} = 2.0V$	0 to 1000	ns
		$V_{CC} = 4.5V$	0 to 500	ns
		$V_{CC} = 6.0V$	0 to 400	ns

5 Electrical characteristics

Table 5. DC specifications

Symbol	Parameter	Test condition		Value						Unit	
		V _{CC} (V)		T _A = 25°C			-40 to 85°C		-55 to 125°C		
				Min.	Typ.	Max.	Min.	Max.	Min.		Max.
V _{IH}	High level input voltage	2.0		1.5			1.5		1.5		V
		4.5		3.15			3.15		3.15		
		6.0		4.2			4.2		4.2		
V _{IL}	Low level input voltage	2.0				0.5		0.5		0.5	V
		4.5				1.35		1.35		1.35	
		6.0				1.8		1.8		1.8	
V _{OH}	High level output voltage	2.0	I _O =-20 μA	1.9	2.0		1.9		1.9		V
		4.5	I _O =-20 μA	4.4	4.5		4.4		4.4		
		6.0	I _O =-20 μA	5.9	6.0		5.9		5.9		
		4.5	I _O =-4.0 mA	4.18	4.31		4.13		4.10		
		6.0	I _O =-5.2 mA	5.68	5.8		5.63		5.60		
V _{OL}	Low level output voltage	2.0	I _O =20 μA		0.0	0.1		0.1		0.1	V
		4.5	I _O =20 μA		0.0	0.1		0.1		0.1	
		6.0	I _O =20 μA		0.0	0.1		0.1		0.1	
		4.5	I _O =4.0 mA		0.17	0.26		0.33		0.40	
		6.0	I _O =5.2 mA		0.18	0.26		0.33		0.40	
I _I	Input leakage current	6.0	V _I = V _{CC} or GND			± 0.1		± 1		± 1	μA
I _{CC}	Quiescent supply current	6.0	V _I = V _{CC} or GND			4		40		80	μA

Table 6. AC electrical characteristics ($C_L = 50$ pF, Input $t_r = t_f = 6$ ns)

Symbol	Parameter	Test condition		Value						Unit	
		V_{CC} (V)		$T_A = 25^\circ\text{C}$			-40 to 85°C		-55 to 125°C		
				Min.	Typ.	Max.	Min.	Max.	Min.		Max.
t_{TLH} t_{THL}	Output transition time	2.0			30	75		95		110	ns
		4.5			8	15		19		22	
		6.0			7	13		16		19	
t_{PLH} t_{PHL}	Propagation delay time (CLOCK - QH, \overline{QH})	2.0			55	150		190		225	ns
		4.5			18	30		38		45	
		6.0			15	26		33		38	
t_{PLH} t_{PHL}	Propagation delay time (SHIFT/ \overline{LOAD} - QH, \overline{QH})	2.0			65	165		205	250		ns
		4.5			21	33		41		50	
		6.0			18	28		35		43	
t_{PLH} t_{PHL}	Propagation delay time (H - QH, \overline{QH})	2.0			52	135		170		205	ns
		4.5			17	27		34		41	
		6.0			14	23		29		35	
fMAX	Maximum clock frequency	2.0		7.4	15		6.0		4.8		MHz
		4.5		37	60		30		24		
		6.0		44	71		35		28		
$t_{W(H)}$ $t_{W(L)}$	Minimum pulse width (CLOCK)	2.0			24	75		95		110	ns
		4.5			6	15		19		22	
		6.0			5	13		16		19	
$t_{W(L)}$	Minimum pulse width (SHIFT/ \overline{LOAD})	2.0			32	75		95		110	ns
		4.5			8	15		19		22	
		6.0			7	13		16		19	
t_s	Minimum set-up time (PI - SHIFT/ \overline{LOAD}) (SI - CLOCK) (SHIFT/ \overline{LOAD} - CK)	2.0			24	75		95		110	ns
		4.5			6	15		19		22	
		6.0			5	13		16		19	
t_h	Minimum hold time (PI - SHIFT/ \overline{LOAD}) (SI - CLOCK) (SHIFT/ \overline{LOAD} - CK)	2.0				0		0		0	ns
		4.5				0		0		0	
		6.0				0		0		0	
t_{REM}	Minimum removal time (CLOCK - CK INH)	2.0			20	75		95		110	ns
		4.5			5	15		19		22	
		6.0			4	13		16		19	

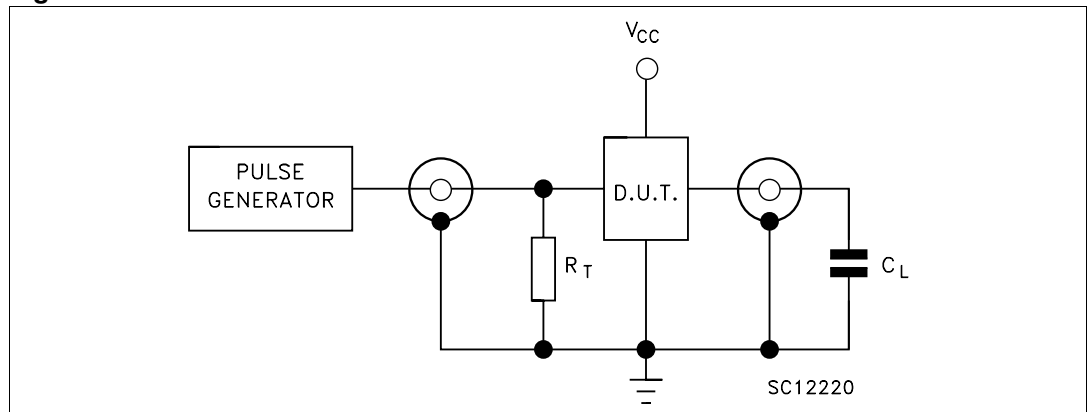
Table 7. Capacitive characteristics

Symbol	Parameter	Test condition		Value						Unit	
		V _{CC} (V)		T _A = 25°C			-40 to 85°C		-55 to 125°C		
				Min.	Typ.	Max.	Min.	Max.	Min.		Max.
C _{IN}	Input capacitance	5.0			5	10		10		10	pF
C _{PD}	Power dissipation capacitance ⁽¹⁾	5.0			55						pF

1. C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation.
 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}$

6 Test circuit

Figure 6. Test circuit



$C_L = 50\text{pF}$ or equivalent (includes jig and probe capacitance)

$R_T = Z_{OUT}$ of pulse generator (typically 50Ω)

7 Waveforms

Figure 7. Serial mode propagation delay (f = 1MHz; 50% duty cycle)

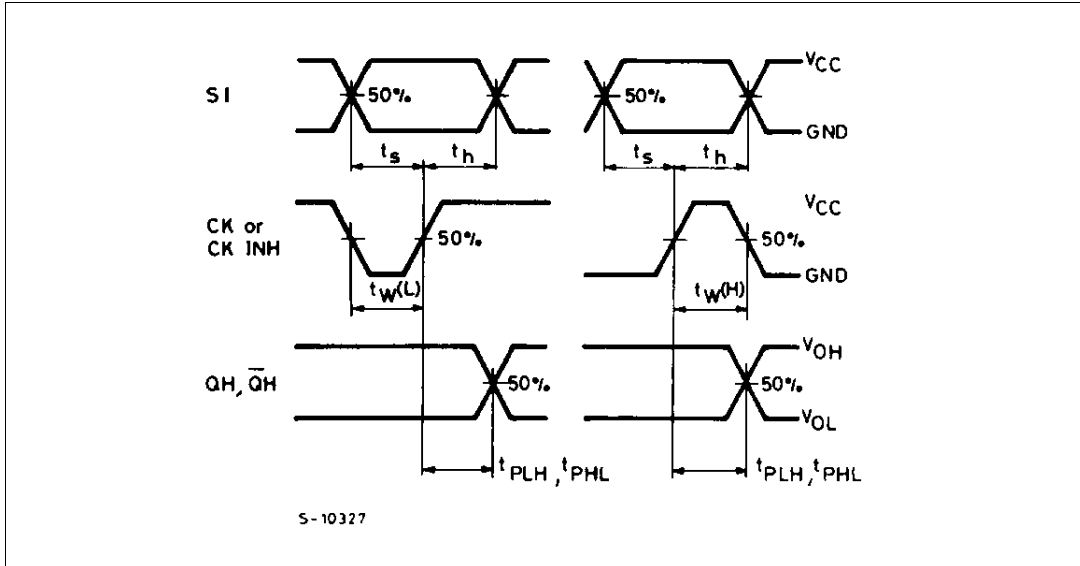


Figure 8. Parallel mode propagation delay (f = 1MHz; 50% duty cycle)

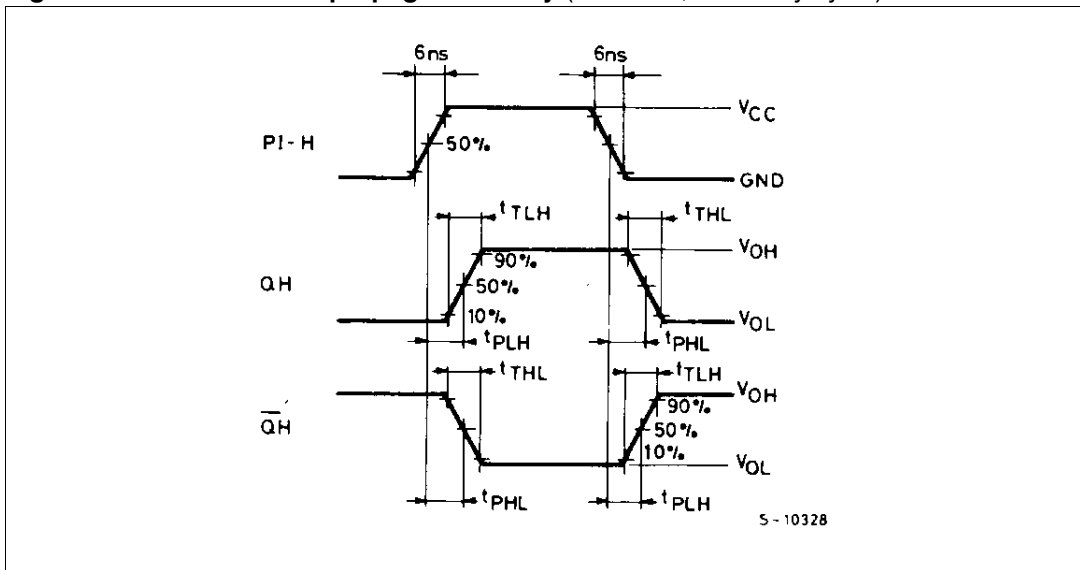


Figure 9. Minimum pulse width (S/\bar{L}), propagation delay times ($f=1\text{MHz}$; 50% duty cycle)

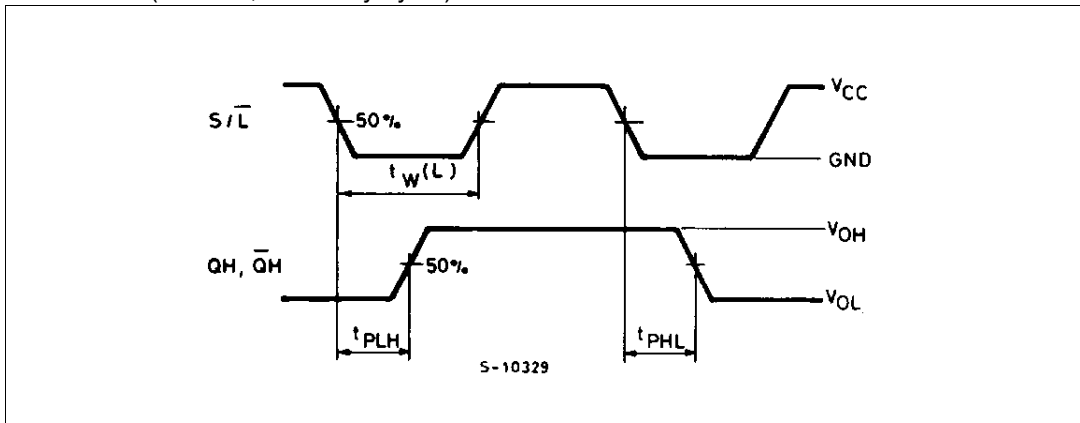


Figure 10. Setup and hold time (PI to S/\bar{L}) ($f = 1\text{MHz}$; 50% duty cycle)

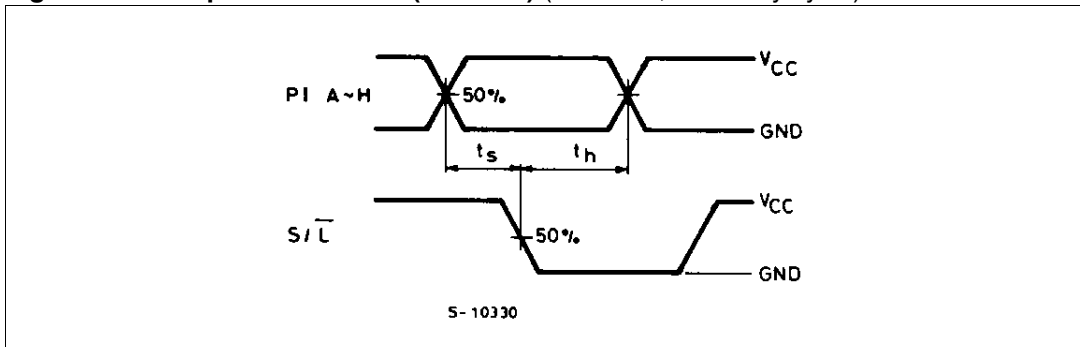
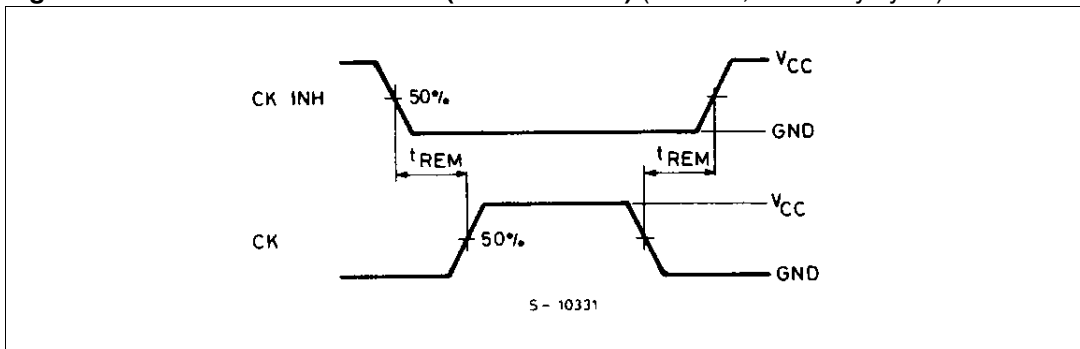


Figure 11. Minimum removal time (CK INH to CK) ($f=1\text{MHz}$; 50% duty cycle)

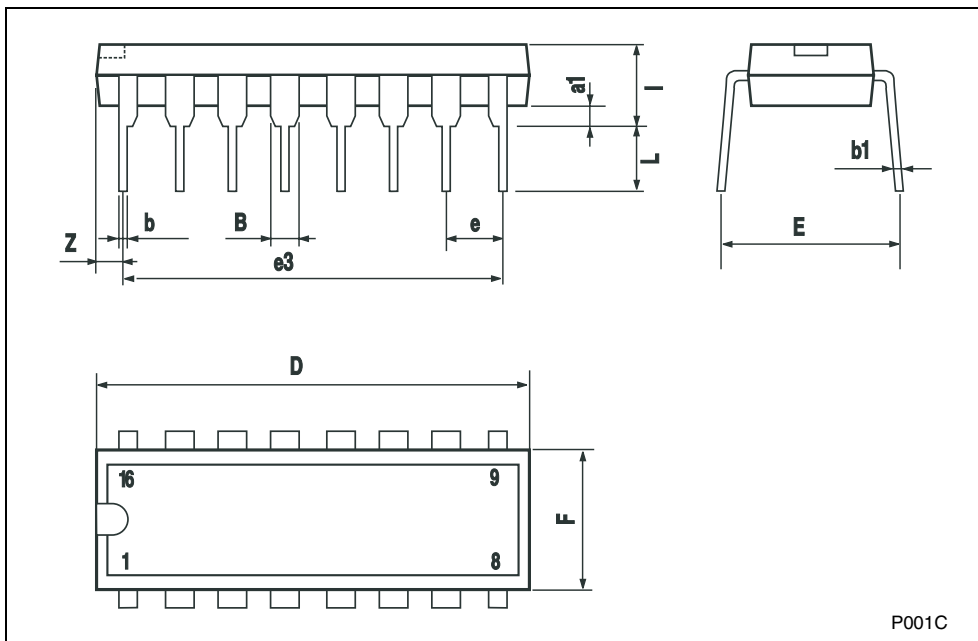


8 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

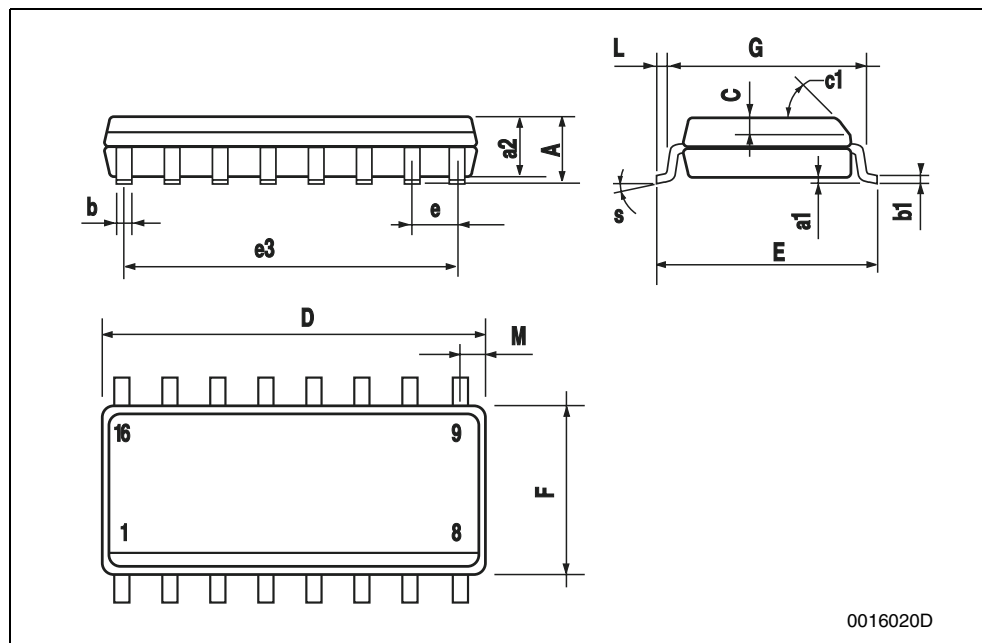
Plastic DIP-16 (0.25) MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050



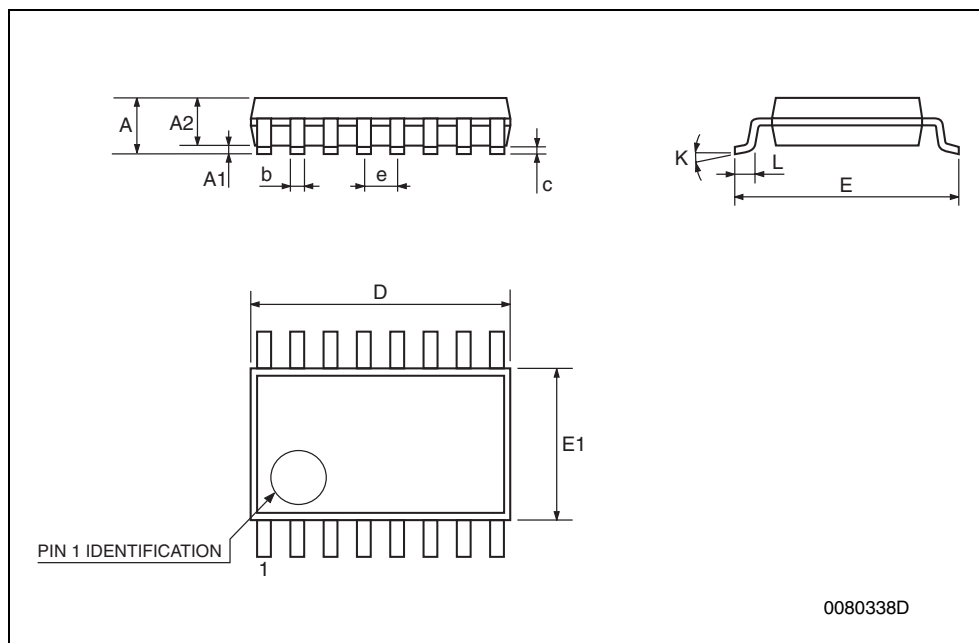
SO-16 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.25	0.004		0.010
a2			1.64			0.063
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45° (typ.)					
D	9.8		10	0.385		0.393
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		8.89			0.350	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.62			0.024
S	8° (max.)					



TSSOP16 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.0079
D	4.9	5	5.1	0.193	0.197	0.201
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
e		0.65 BSC			0.0256 BSC	
K	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030



9 Revision history

Table 8. Revision history

Date	Revision	Changes
9-Jul-2001	3	Final release
21-Mar-2007	4	The document has been reformatted, updated Table 1: Pin description on page 4

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